



BUK652R0-30C,127 Information

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For Reference Only

Part Number BUK652R0-30C,127

Manufacturer NXP

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 30V 120A TO220AB

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









BUK652R0-30C,127 Specifications

Manufacturer Part Number	BUK652R0-30C,127
Manufacturer	NXP
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	TrenchMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	120A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.8V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	229nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	14964pF @ 25V
Vgs (Max)	±16V
FET Feature	-
Power Dissipation (Max)	306W (Tc)
Rds On (Max) @ Id, Vgs	2.2 mOhm @ 25A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220AB
Package / Case	TO-220-3
	Report errors?

BUK652R0-30C,127 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BUK652R0-30C,127 Payment Methods



















BUK652R0-30C,127 Shipping Methods













If you have any question about BUK652R0-30C,127, please do not hesitate to contact us!

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